HD74LS75

Quadruple Bistable Latches

REJ03D0416-0300
Rev.3.00
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The HD74LS75 is ideally suited for use as temporary storage for binary information between processing units and input / output or indicator units. Information present at a data (D) input is transferred to the Q output when the enable (G) is high and the Q output will follow the data input as long as the enable remains high. When the enable goes low, the information (that was present at the data input at the time the transition occurred) is retained at the Q output until the enable is permitted to go high. This device features complementary Q and $\overline{Q}$ outputs from a 4-bit latch.

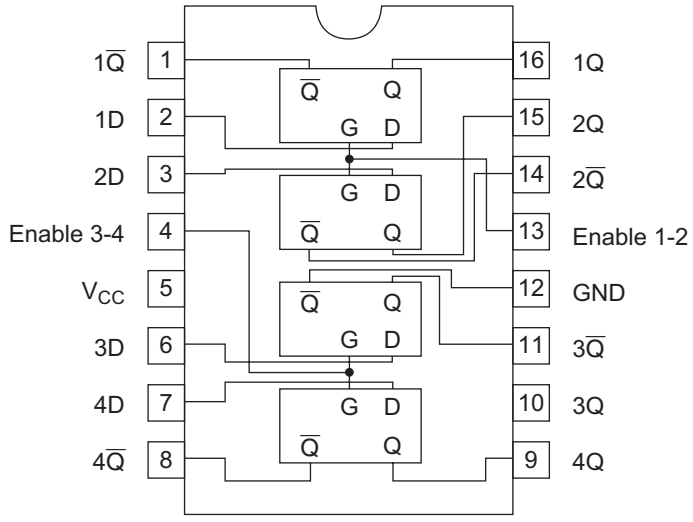
Features

- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS75P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	P	—
HD74LS75FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Pin Arrangement



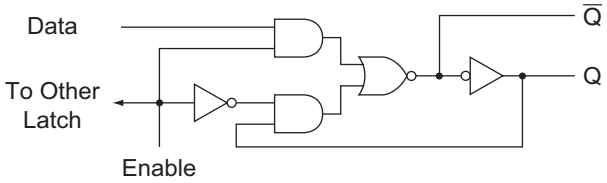
(Top view)

Function Table

Inputs		Outputs	
D	G	Q	$\overline{Q}$
L	H	L	H
H	H	H	L
X	L	Q_0	$\overline{Q}_0$

H; high level, L; low level, X; irrelevant
Q_0; level of Q before the indicated steady-state input conditions were established.
$\overline{Q}_0$; complement of Q_0 or level of $\overline{Q}_0$ before the indicated steady-state input conditions were established.

Circuit Schematic (1/4)



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V_{CC}	7	V
Input voltage	V_{IN}	7	V
Power dissipation	P_T	400	mW
Storage temperature	Tstg	–65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.75	5.00	5.25	V
Output current	I_{OH}	—	—	–400	µA
	I_{OL}	—	—	8	mA
Operating temperature	Topr	–20	25	75	°C
Pulse width	tw	20	—	—	ns
Setup time	tsu	15	—	—	ns
Hold time	th	5	—	—	ns

Electrical Characteristics

(Ta = –20 to +75 °C)

Item		Symbol	min.	typ.*	max.	Unit	Condition
Input voltage		V_{IH}	2.0	—	—	V	
		V_{IL}	—	—	0.8	V	
Output voltage		V_{OH}	2.7	—	—	V	V_{CC} = 4.75 V, V_{IH} = 2 V, V_{IL} = 0.8 V, I_{OH} = –400 µA
		V_{OL}	—	—	0.4	V	I_{OL} = 4 mA, V_{CC} = 4.75 V, V_{IH} = 2 V, V_{IL} = 0.8 V
			—	—	0.5		I_{OL} = 8 mA
Input current	D input	I_{IH}	—	—	20	µA	V_{CC} = 5.25 V, V_I = 2.7 V
	G input		—	—	80		
	D input	I_{IL}	—	—	–0.4	mA	V_{CC} = 5.25 V, V_I = 0.4 V
	G input		—	—	–1.6		
	D input	I_I	—	—	0.1	mA	V_{CC} = 5.25 V, V_I = 7 V
	G input		—	—	0.4		
Short-circuit output current		I_{OS}	–20	—	–100	mA	V_{CC} = 5.25 V
Supply current**		I_{CC}	—	6.3	12	mA	V_{CC} = 5.25 V
Input clamp voltage		V_{IK}	—	—	–1.5	V	V_{CC} = 4.75 V, I_{IN} = –18 mA

Notes: * V_{CC} = 5 V, Ta = 25°C

** I_{CC} is measured with all outputs open and all inputs grounded.

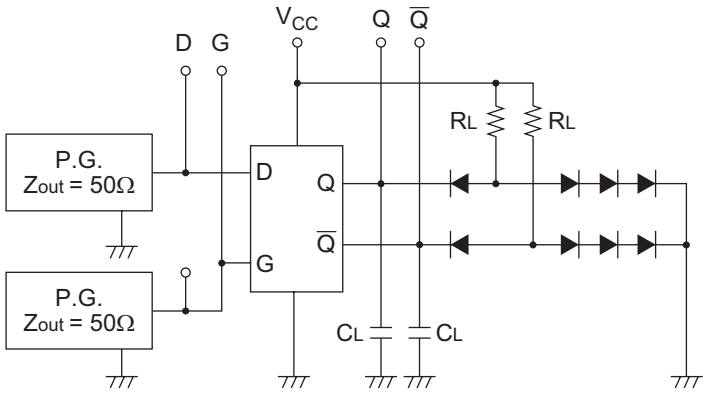
Switching Characteristics

(V_{CC} = 5 V, Ta = 25°C)

Item	Symbol	Inputs	Outputs	min.	typ.	max.	Unit	Condition
Propagation delay time	t_{PLH}	D	Q	—	15	27	ns	C_L = 15 pF, R_L = 2 kΩ
	t_{PHL}			—	9	17		
	t_{PLH}	D	$\overline{Q}$	—	12	20	ns	
	t_{PHL}			—	7	15		
	t_{PLH}	G	Q	—	15	27	ns	
	t_{PHL}			—	14	25		
	t_{PLH}	G	$\overline{Q}$	—	16	30	ns	
	t_{PHL}			—	7	15		

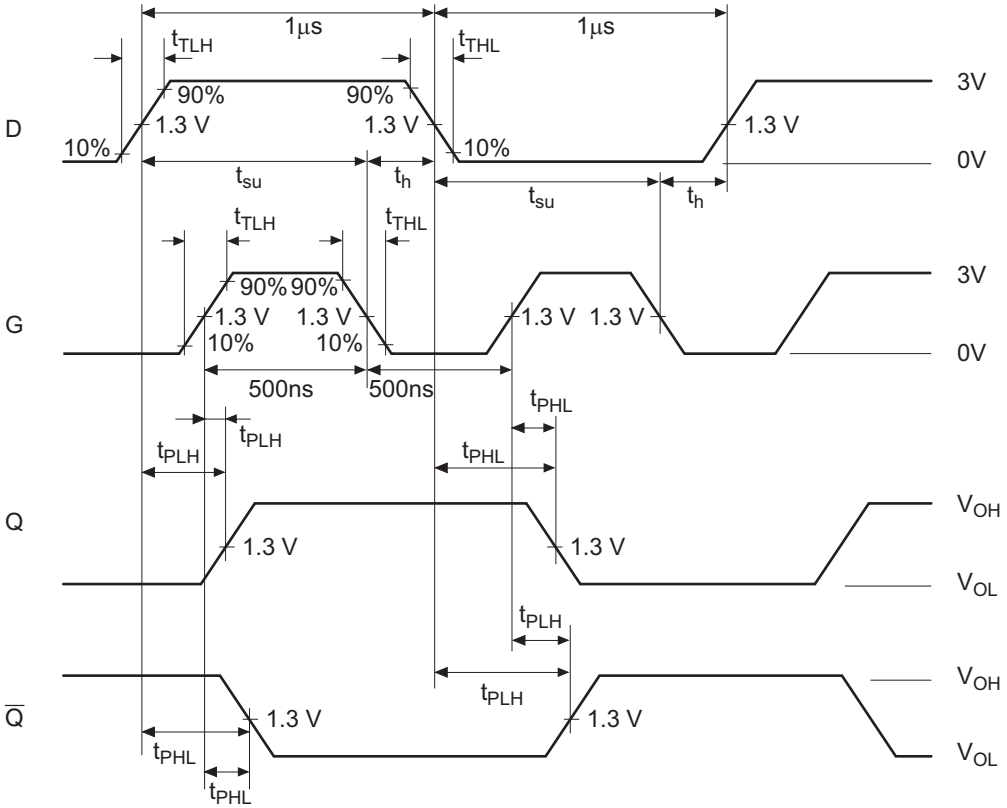
Testing Method

Test Circuit



Notes:
1. Test is put into the each flip-flop.
2. C_L includes probe and jig capacitance.
3. All diodes are 1S2074(H).

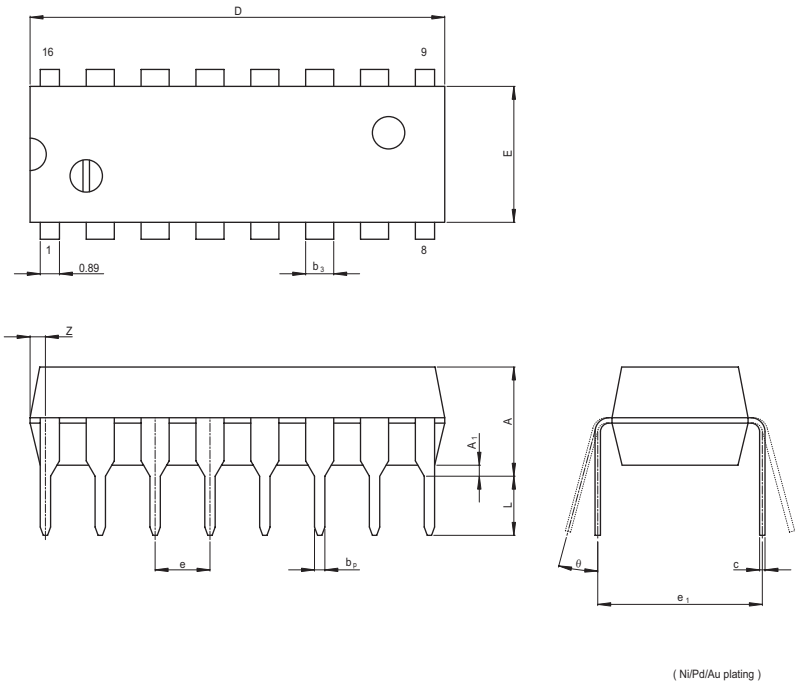
Waveform



Notes:
1. Input pulse; D input: PRR = 500 kHz, G input; PRR = 1 MHz, $t_{THL} \leq 10$ ns, $t_{TLH} \leq 10$ ns.
2. When measuring propugation delay times from the D input, the corresponding G input must be held high.

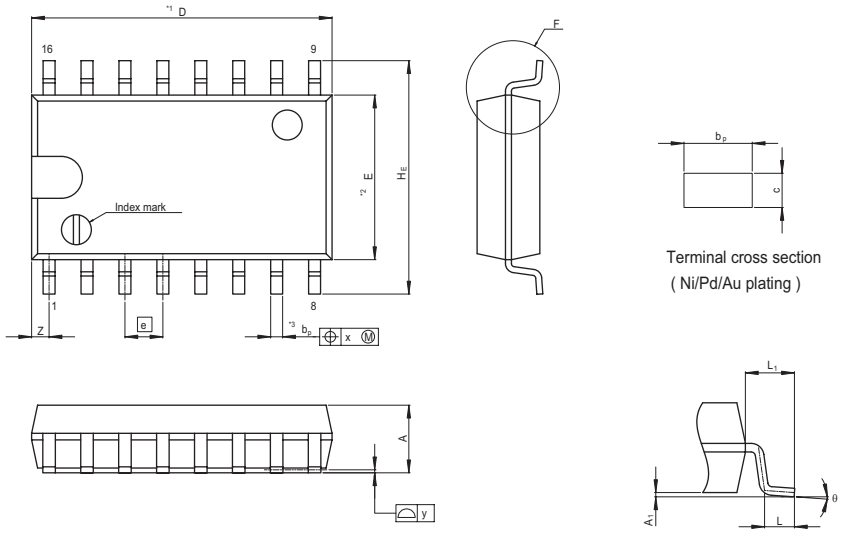
Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-DIP16-6.3x19.2-2.54	PRDP0016AE-B	DP-16FV	1.05g



Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
e_1	—	7.62	—
D	—	19.2	20.32
E	—	6.3	7.4
A	—	—	5.06
A_1	0.51	—	—
b_p	0.40	0.48	0.56
b_3	—	1.30	—
c	0.19	0.25	0.31
θ	0°	—	15°
e	2.29	2.54	2.79
Z	—	—	1.12
L	2.54	—	—

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-SOP16-5.5x10.06-1.27	PRSP0016DH-B	FP-16DAV	0.24g



NOTE)
1. DIMENSIONS"*1 (Nom)"AND"*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION"*3"DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	10.06	10.5
E	—	5.50	—
A_2	—	—	—
A_1	0.00	0.10	0.20
A	—	—	2.20
b_p	0.34	0.40	0.46
b_1	—	—	—
c	0.15	0.20	0.25
c_1	—	—	—
θ	0°	—	8°
H_E	7.50	7.80	8.00
e	—	1.27	—
x	—	—	0.12
y	—	—	0.15
Z	—	—	0.80
L	0.50	0.70	0.90
L_1	—	1.15	—

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RENESAS SALES OFFICES

http://www.renesas.com

Refer to "**http://www.renesas.com/en/network**" for the latest and detailed information.

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